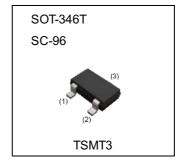


NPN 3.0A 50V Middle Power Transistor

Parameter	Value			
V _{CEO}	50V			
IC	3A			

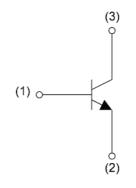
Outline



Features

- 1)Suitable for Middle Power Transistor
- 2) Complementary PNP Types:2SAR543R
- 3) Low saturation voltage, typically $V_{CE(sat)}$ =350mV(Max.) $(I_C/I_B$ =2A/100mA)

•Inner circuit



- (1) Base
- (2) Emitter
- (3) Collector

Application

LOW FREQUENCY AMPLIFIER, HIGH SPEED SWITCHING

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SCR543R	SOT-346T (TSMT3)	2928	TL	180	8	3000	NR

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I _C	3	Α
Collector current	I _{CP} *1	6	Α
Down discinction	P _D *2	0.5	W
Power dissipation	P _D *3	1.0	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Cumbal	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I _C = 100μA	50	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = 100μA	6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	-	-	1.0	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 4V	-	-	1.0	μA
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 2A, I _B = 100mA	-	130	350	mV
DC current gain	h _{FE}	$V_{CE} = 3V, I_{C} = 100 \text{mA}$	180	-	450	-
Transition frequency	f _T	$V_{CE} = 10V, I_{E} = -500 \text{mA},$ f = 100MHz	-	300	-	MHz
Output capacitance	C _{ob}	$V_{CB} = 10V, I_{E} = 0A,$ f = 1MHz	-	20	-	pF
Turn-On time	t _{on}	I _C = 2A, I _{B1} = 200mA,	-	50	-	ns
Storage time	t _{stg}	$I_{B2} = -200 \text{mA},$ $V_{CC} \approx 10 \text{V},$	-	450	-	ns
Fall time	t _f	$R_L = 4.7\Omega$ See test circuit	-	85	-	ns

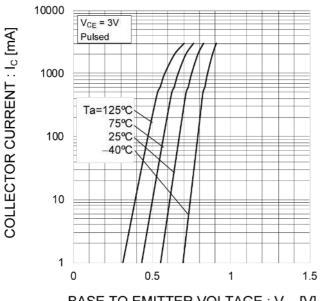
^{*1} P_W=10ms, Single pulse

^{*2} Each terminal mounted on a reference land.

^{*3} Mounted on a 40×40×0.7mm ceramic board.

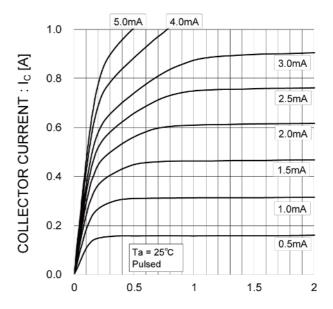
● Electrical characteristic curves(T_a = 25°C)

Fig.1 Ground Emitter Propagation Characteristics



BASE TO EMITTER VOLTAGE: VBE [V]

Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: VCE [V]

Fig.3 DC Current Gain vs. Collector Current (I)

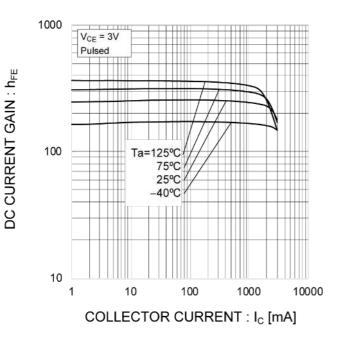
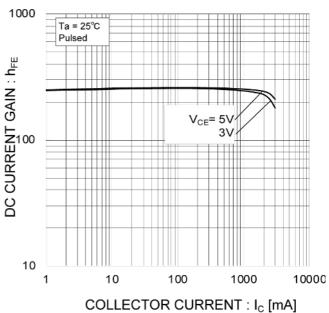


Fig.4 DC Current Gain vs. Collector Current (II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

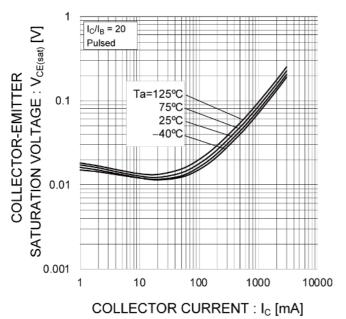


Fig.6 Collector-Emitter Saturation
Voltage vs. Collector Current (II)

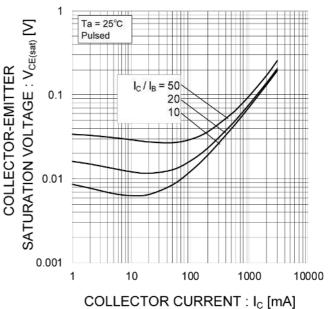


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

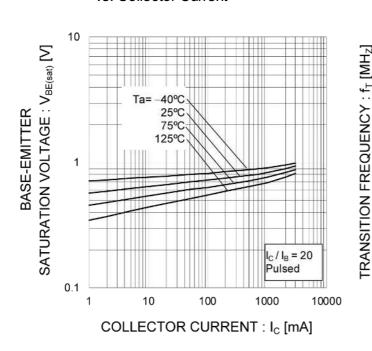
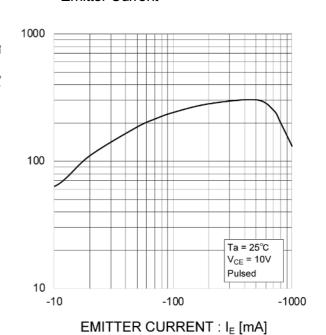


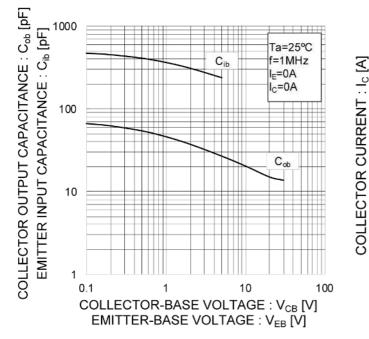
Fig.8 Gain Bandwidth Product vs. Emitter Current

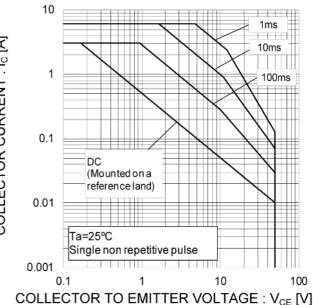


● Electrical characteristic curves(T_a = 25°C)

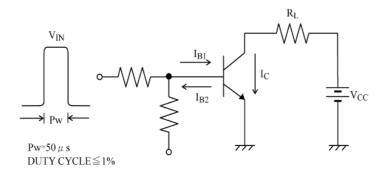
Fig.9 Emitter Input Capacitance vs.
Emitter-Base Voltage
Collector Output Capacitance vs.
Collector-Base Voltage

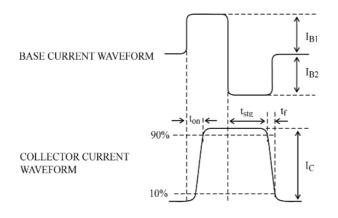
Fig.10 Safe Operating Area





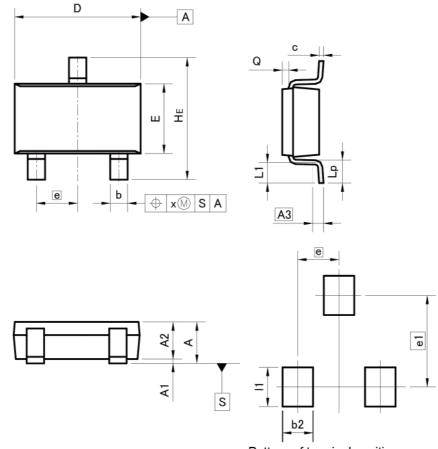
SWITCHING TIME TEST CIRCUIT





Dimensions

TSMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

MILIMI	ETERS	INCHES				
MIN	MAX	MIN	MAX			
-	1.00	-	0.039			
0.00	0.10	0.000	0.004			
0.75	0.95	0.030	0.037			
0.5	25	0.010				
0.35	0.50	0.014	0.020			
0.10	0.26	0.004	0.010			
2.80	3.00	0.110	0.118			
1.50	1.80	0.059	0.071			
0.9	95	0.037				
2.60	3.00	0.102	0.118			
0.30	0.60	0.012	0.024			
0.40	0.70	0.016	0.028			
0.05	0.25	0.002	0.010			
-	0.20	-	0.008			
MILIM	ETERS	INCHES				
MIN	MAX	MIN	MAX			
	0.70	_	0.028			
2.	10	0.083				
	MIN - 0.00 0.75 0.35 0.10 2.80 1.50 0.2.60 0.30 0.40 0.05 - MILIMI MIN	- 1.00 0.00 0.10 0.75 0.95 0.25 0.35 0.50 0.10 0.26 2.80 3.00 1.50 1.80 0.95 2.60 3.00 0.30 0.60 0.40 0.70 0.05 0.25 - 0.20 MILIMETERS MIN MAX	MIN MAX MIN - 1.00 - 0.00 0.10 0.000 0.75 0.95 0.030 0.25 0.0 0.35 0.50 0.014 0.10 0.26 0.004 2.80 3.00 0.110 1.50 1.80 0.059 0.95 0.0 2.60 3.00 0.102 0.30 0.60 0.012 0.40 0.70 0.016 0.05 0.25 0.002 - 0.20 - MILIMETERS INCI			

Dimension in mm/inches

11



0.035

0.90

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